25AA1024

1 Mbit SPI Bus Serial EEPROM

Device Selection Table

Part Number	Vcc Range	Page Size	Temp. Ranges	Packages
25AA1024	1.8-5.5V	256 Byte	_	P, SM, MF

Features:

- · 20 MHz max. Clock Speed
- Byte and Page-level Write Operations:
 - 256 byte page
 - 6 ms max. write cycle time
 - No page or sector erase required
- Low-Power CMOS Technology:
 - Max. Write current: 5 mA at 5.5V, 20 MHz
 - Read current: 7 mA at 5.5V, 20 MHz
 - Standby current: 1µA at 2.5V (Deep power-down)
- · Electronic Signature for Device ID
- · Self-Timed Erase and Write Cycles:
 - Page Erase (6 ms max.)
 - Sector Erase (10 ms max.)
 - Chip Erase (10 ms max.)
- Sector Write Protection (32K byte/sector):
 - Protect none, 1/4, 1/2 or all of array
- Built-In Write Protection:
 - Power-on/off data protection circuitry
 - Write enable latch
 - Write-protect pin
- · High Reliability:
 - Endurance: 1M erase/write cycles
 - Data Retention: >200 years
 - ESD Protection: 4000V
- Temperature Ranges Supported:
 - Industrial (I): -40°C to +85°C
- · Pb-free and RoHS Compliant

Pin Function Table

Name	Function			
CS	Chip Select Input			
SO	Serial Data Output			
WP	Write-Protect			
Vss	Ground			
SI	Serial Data Input			
SCK	Serial Clock Input			
HOLD	Hold Input			
Vcc	Supply Voltage			

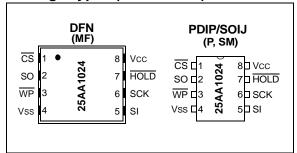
Description:

The Microchip Technology Inc. 25AA1024 is a 1024 Kbit serial EEPROM memory with byte-level and page-level serial EEPROM functions. It also features Page, Sector and Chip erase functions typically associated with Flash-based products. These functions are not required for byte or page write operations. The memory is accessed via a simple Serial Peripheral Interface (SPI) compatible serial bus. The bus signals required are a clock input (SCK) plus separate data in (SI) and data out (SO) lines. Access to the device is controlled by a Chip Select ($\overline{\text{CS}}$) input.

Communication to the device can be paused via the hold pin (HOLD). While the device is paused, transitions on its inputs will be ignored, with the exception of Chip Select, allowing the host to service higher priority interrupts.

The 25AA1024 is available in standard packages including 8-lead PDIP and SOIJ, and advanced 8-lead DFN package. All devices are Pb-free.

Package Types (not to scale)



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings (†)

† NOTICE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for an extended period of time may affect device reliability.

TABLE 1-1: DC CHARACTERISTICS

DC CHARACTERISTICS		Industrial (I)*: TA = 0° C to +85°C					
Param. No. Characteristic		Min.	Max.	Units	Test Conditions		
D001	VIH1	High-level input voltage	.7 Vcc	Vcc +1	V		
D002	VIL1	Low-level input	-0.3	0.3 Vcc	V	Vcc ≥ 2.7V	
D003	VIL2	voltage	-0.3	0.2 Vcc	V	Vcc < 2.7V	
D004	Vol	Low-level output	_	0.4	V	IOL = 2.1 mA	
D005	Vol	voltage	_	0.2	V	IOL = 1.0 mA, VCC < 2.5V	
D006	Voн	High-level output voltage	Vcc -0.2	_	V	ΙΟΗ = -400 μΑ	
D007	ILI	Input leakage current	_	±1	μΑ	CS = Vcc, Vin = Vss to Vcc	
D008	ILO	Output leakage current	_	±1	μА	CS = Vcc, Vout = Vss to Vcc	
D009	CINT	Internal capacitance (all inputs and outputs)	_	7	pF	TA = 25°C, CLK = 1.0 MHz, VCC = 5.0V (Note)	
D010	Icc Read		_	10	mA	Vcc = 5.5V; Fclk = 20.0 MHz;	
		Operating current	_	5	mA	SO = Open VCC = 2.5V; FCLK = 10.0 MHz; SO = Open	
D011	Icc Write		_	7	mA	Vcc = 5.5V	
			_	5	mA	Vcc = 2.5V	
D012	Iccs	Standby current		12	μΑ	CS = Vcc = 5.5V, Inputs tied to Vcc or Vss, 85°C	
D13	ICCSPD	Deep power-down current		1	μА	CS = Vcc = 2.5V, Inputs tied to Vcc or Vss, 85°C	

Note: This parameter is periodically sampled and not 100% tested.

TABLE 1-2: AC CHARACTERISTICS

AC CHARACTERISTICS		Industrial (I)*: TA = 0°C to +85 Industrial (I): TA = -40°C to +8 *Limited industrial temp range.						
Param. No.	Sym Characteristic		Min.	Max.	Units	Conditions		
1	FCLK	Clock frequency	_ _ _	20 10 2	MHz MHz MHz	4.5 ≤ VCC ≤ 5.5 2.5 ≤ VCC < 5.5 1.8 ≤ VCC < 2.5 at 0°C to +85°C 2.0 ≤ VCC < 2.5 at -40°C to +85°C		
2	Tcss	CS setup time	25 50 250	_ _ _	ns ns ns	4.5 ≤ VCC ≤ 5.5 2.5 ≤ VCC < 5.5 1.8 ≤ VCC < 2.5 at 0°C to +85°C 2.0 ≤ VCC < 2.5 at -40°C to +85°C		
3	Тсѕн	CS hold time	50 100 500	_ _ _	ns ns ns	4.5 ≤ VCC ≤ 5.5 2.5 ≤ VCC < 5.5 1.8 ≤ VCC < 2.5 at 0°C to +85°C 2.0 ≤ VCC < 2.5 at -40°C to +85°C (Note 3)		
4	TCSD	CS disable time	50		ns	_		
5	Tsu	Data setup time	5 10 50	_ _ _	ns ns ns	4.5 ≤ VCC ≤ 5.5 2.5 ≤ VCC < 5.5 1.8 ≤ VCC <2.5 at 0°C to +85°C 2.0 ≤ VCC <2.5 at -40°C to +85°C		
6	THD	Data hold time	10 20 100	_ _ _	ns ns ns	4.5 ≤ VCC ≤ 5.5 2.5 ≤ VCC < 5.5 1.8 ≤ VCC < 2.5 at 0°C to +85°C 2.0 ≤ VCC < 2.5 at -40°C to +85°C		
7	TR	CLK rise time	_	20	ns	(Note 1)		
8	TF	CLK fall time	_	20	ns	(Note 1)		
9	Тні	Clock high time	25 50 250	_ _ _	ns ns ns	4.5 ≤ Vcc ≤ 5.5 2.5 ≤ Vcc < 5.5 1.8 ≤ Vcc <2.5 at 0°C to +85°C 2.0 ≤ Vcc <2.5 at -40°C to +85°C		
10	TLO	Clock low time	25 50 250	_ _	ns ns ns	4.5 ≤ VCC ≤ 5.5 2.5 ≤ VCC < 5.5 1.8 ≤ VCC <2.5 at 0°C to +85°C 2.0 ≤ VCC <2.5 at -40°C to +85°C		
11	TCLD	Clock delay time	50	_	ns	_		
12	TCLE	Clock enable time	50	_	ns	_		
13	Tv	Output valid from clock low	_ _ _	25 50 250	ns ns ns	4.5 ≤ VCC ≤ 5.5 2.8 ≤ VCC < 5.5 1.8 ≤ VCC < 2.5 at 0°C to +85°C 2.0 ≤ VCC < 2.5 at -40°C to +85°C		
14	Тно	Output hold time	0	_	ns	(Note 1)		

Note 1: This parameter is periodically sampled and not 100% tested.

- 2: This parameter is not tested but established by characterization and qualification. For endurance estimates in a specific application, please consult the Total Endurance™ Model which can be obtained from Microchip's web site
- 3: Includes THI time.

TABLE 1-2: AC CHARACTERISTICS (CONTINUED)

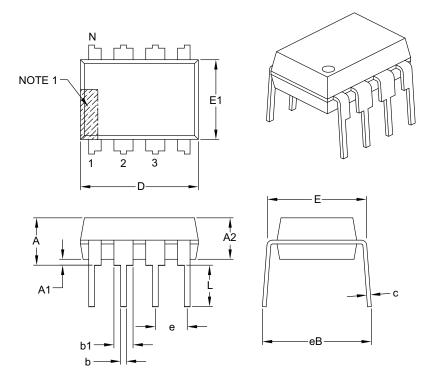
AC CHARACTERISTICS		Industrial (I)*: TA = 0° C to +85°C				
Param. No.	Sym.	Characteristic	Min.	Max.	Units	Conditions
15	TDIS	Output disable time	_ _ _	25 50 250	ns ns ns	4.5 ≤ VCC ≤ 5.5 2.5 ≤ VCC < 5.5 1.8 ≤ VCC <2.5 at 0°C to +85°C 2.0 ≤ VCC <2.5 at -40°C to +85°C (Note 1)
16	THS	HOLD setup time	10 20 100	_ _ _	ns ns ns	4.5 ≤ VCC ≤ 5.5 2.5 ≤ VCC < 5.5 1.8 ≤ VCC <2.5 at 0°C to +85°C 2.0 ≤ VCC <2.5 at -40°C to +85°C
17	Тнн	HOLD hold time	10 20 100		ns ns ns	4.5 ≤ VCC ≤ 5.5 2.5 ≤ VCC < 5.5 1.8 ≤ VCC <2.5 at 0°C to +85°C 2.0 ≤ VCC <2.5 at -40°C to +85°C
18	THZ	HOLD low to output High-Z	15 30 150	_ _ _	ns ns ns	4.5 ≤ VCC ≤ 5.5 2.5 ≤ VCC < 4.5 1.8 ≤ VCC < 2.5 at 0°C to +85°C 2.0 ≤ VCC < 2.5 at -40°C to +85°C (Note 1)
19	THV	HOLD high to output valid	15 30 150	= =	ns ns ns	4.5 ≤ VCC ≤ 5.5 2.5 ≤ VCC < 4.5 1.8 ≤ VCC <2.5 at 0°C to +85°C 2.0 ≤ VCC <2.5 at -40°C to +85°C
20	TREL	CS High to Standby mode	_	100	μS	Vcc = 1.8V to 5.5V
21	TPD	CS High to Deep power- down	_	100	μS	VCC = 1.8V to 5.5V
22	TCE	Chip erase cycle time	_	10	ms	Vcc = 1.8V to 5.5V
23	TSE	Sector erase cycle time	_	10	ms	VCC = 1.8V to 5.5V
24	Twc	Internal write cycle time	_	6	ms	Byte or Page mode and Page Erase
25	_	Endurance	1M	_	E/W Cycles	(Note 2) Per Page

Note 1: This parameter is periodically sampled and not 100% tested.

3: Includes THI time.

^{2:} This parameter is not tested but established by characterization and qualification. For endurance estimates in a specific application, please consult the Total Endurance™ Model which can be obtained from Microchip's web site

8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]



	Units		INCHES		
	Dimension Limits	MIN	NOM	MAX	
Number of Pins	N		8		
Pitch	е		.100 BSC		
Top to Seating Plane	A	_	_	.210	
Molded Package Thickness	A2	.115	.130	.195	
Base to Seating Plane	A1	.015	_	-	
Shoulder to Shoulder Width	E	.290	.310	.325	
Molded Package Width	E1	.240	.250	.280	
Overall Length	D	.348	.365	.400	
Tip to Seating Plane	L	.115	.130	.150	
Lead Thickness	С	.008	.010	.015	
Upper Lead Width	b1	.040	.060	.070	
Lower Lead Width	b	.014	.018	.022	
Overall Row Spacing §	eB	_	_	.430	

Notes:

- 1. Pin 1 visual index feature may vary, but must be located with the hatched area.
- 2. § Significant Characteristic.
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-018B

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	X	- <u>X</u> <u>/XX</u>	Exa	amples:
Device	Tape & Re	el Temp Range Package	a)	25AA1024T-I/SM EEPROM, Indust package
Device:	25AA1024	1 Mbit, 1.8V, 256-Byte Page SPI Serial EEPROM	b)	25AA1024T-I/MF EEPROM, Indust package
Tape & Reel:	Blank = T =	Standard packaging (tube) Tape & Reel		parage.
Temperature Range:	I =	-40°C to+85°C		
Package:	MF = P = SM =	Micro Lead Frame (6 x 5 mm body), 8-lead Plastic DIP (300 mil body), 8-lead Plastic SOIJ (5.28 mm), 8-lead		

- a) 25AA1024T-I/SM = 1 Mbit, 1.8V Serial EEPROM, Industrial temp., Tape & Reel, SOIJ package
- b) 25AA1024T-I/MF = 1 Mbit, 1.8V Serial EEPROM, Industrial temp., Tape & Reel, DFN package